NSN 5961-01-139-2986

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-139-2986 **Inclosure Material:** Ceramic **Overall Length:** 1.150 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 15.00 amperes drain current horsepower metric and 150.00 amperes drain current watts **Power Rating Per Characteristic:** 500.0 milliwatts any acceptable preset **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No